

### Description

The HTH8G02P550S(B) is an unmatched discrete LDMOS Power Amplifier with 550W saturated output power covering frequency range from 1.8 - 200 MHz.

### Features

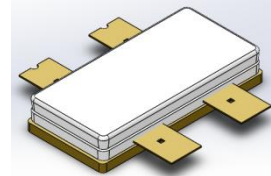
- Operating Frequency Range: 1.8 - 200 MHz
- Operating Drain Voltage: 28-50V
- Saturation Output Power: 550W
- Internally Unmatched device
- Excellent thermal stability due to low thermal resistance package
- Enhanced robustness design without device degradation
- Internally integrated enhanced ESD design

### Applications

- HF VHF band High Power Amplifier
- Broadcasting transmitter
- Industrial Scientific Medical (ISM)
  - Laser generation
  - Plasma generation
  - Particle accelerators
  - MRI, RF ablation and skin treatment
  - Industrial heating, welding and drying systems

### Ordering Information

Part Number	Description
HTH8G02P550S(B)	Tray Package
HTH8G02P550S(B)EVB	100 MHz EVB

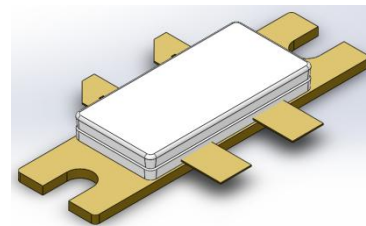


**ACS2110S-4L**

Earless Flanged

Air Cavity Splice Package; 4 Leads

**HTH8G02P550S**



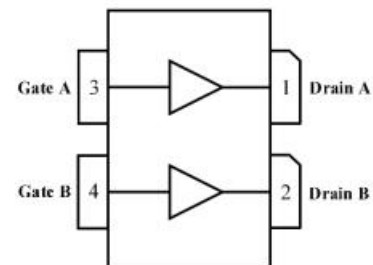
**ACS2110B-4L**

Flanged balanced

Air Cavity Splice Package; 4 Leads,

2 Mounting holes

**HTH8G02P550SB**



(Top View)

Note: Exposed backside of the package is the source terminal for the transistor

**Pin Connections**

### Typical Performance

#### RF Characteristics (CW)

Freq (MHz)	P3dB (dBm)	P3dB (W)	Gain (dB)	Eff(%)@P3dB
100	57.54	558	25.28	70

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ = 300mA test on WATECH Application Board

#### RF Characteristics (Pulsed-CW)

Freq (MHz)	P3dB (dBm)	P3dB (W)	Gain (dB)	Eff(%)@P3dB
100	57.82	580	25.32	75

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ = 300mA, PW = 100us, DC = 10% test on WATECH Application Board

### Absolute Maximum Ratings

Parameter	Range/Value	Unit
Drain voltage (V <sub>DSS</sub> )	-0.5 to +135	V
Gate voltage (V <sub>GS</sub> )	-5 to +10	V
Operating Voltage (V <sub>DS</sub> )	0 to +50	
Storage Temperature (T <sub>STG</sub> )	-55 to +150	°C
Junction Temperature (T <sub>J</sub> )	-40 to +225	°C

### Electrical Specification

#### DC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Breakdown Voltage V <sub>(BR)DSS</sub>	V <sub>gs</sub> =0V, I <sub>ds</sub> =380uA	-	135	-	V
Gate-Source Threshold Voltage V <sub>GS(th)</sub>	V <sub>ds</sub> =10V, I <sub>ds</sub> =380uA	1.5	2.25	2.9	V
Drain Leakage Current I <sub>DSS</sub>	V <sub>gs</sub> =0V, V <sub>ds</sub> =50V	-	1	10	uA
Gate Leakage Current I <sub>GSS</sub>	V <sub>gs</sub> =5V, V <sub>ds</sub> =0V	-	0.1	1	uA

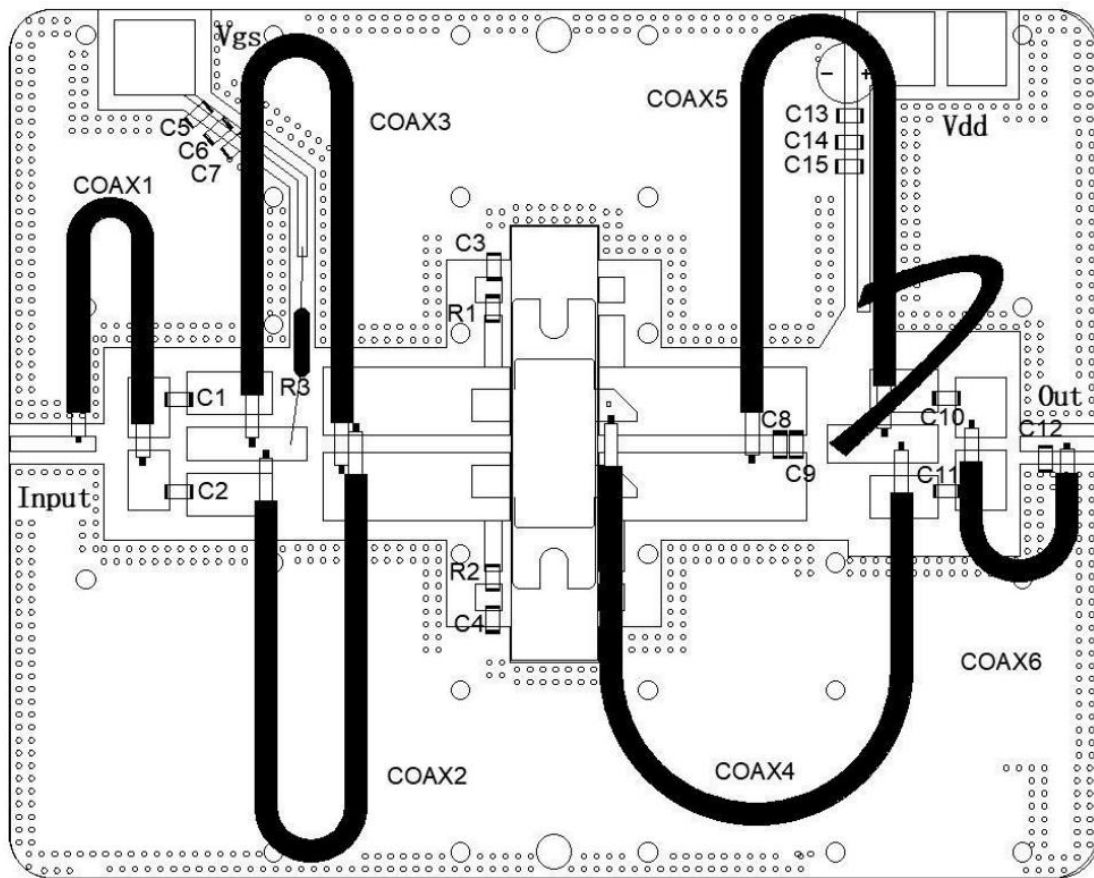
#### Load Mismatch Test

Condition	Test Result
VSWR=65:1 at all Phase Angles, V <sub>DD</sub> = +50Vdc, I <sub>DQ</sub> =300mA, P <sub>out</sub> = 550W, PW = 200us, DC = 20%, freq@100 MHz	No Device Degradation

### Thermal Information

Parameter	Condition	Value (Typ)	Unit
Thermal Resistance Junction to Case ( $R_{TH}$ )	$T_{FLANGE} = 45^{\circ}C$ , $V_{DD} = +50Vdc$ , $I_{DQ} = 300mA$ , CW, $P_{AVG} = 57.4 dBm$ (550W), freq@100 MHz	0.12	$^{\circ}C / W$

### HTH8G02P550S(B) 100 MHz Reference Design



EVB Layout

### Bill of Materials (BoM) - HTH8G02P550S(B) 100 MHz Reference Design

Reference	Value	Description	Manufacturer	P/N
Q1	-	550W, 1.8 - 200 MHz LDMOS PA	Watech	HTH8G02P550H(B)
C5,C13	4u7F	MLCC	Murata	GRM31CR71H475KA12L
C1,C2,C10,C11	300pF	MLCC	ATC	ATC100B301JT
C8	10pF	MLCC	ATC	ATC100B100JT



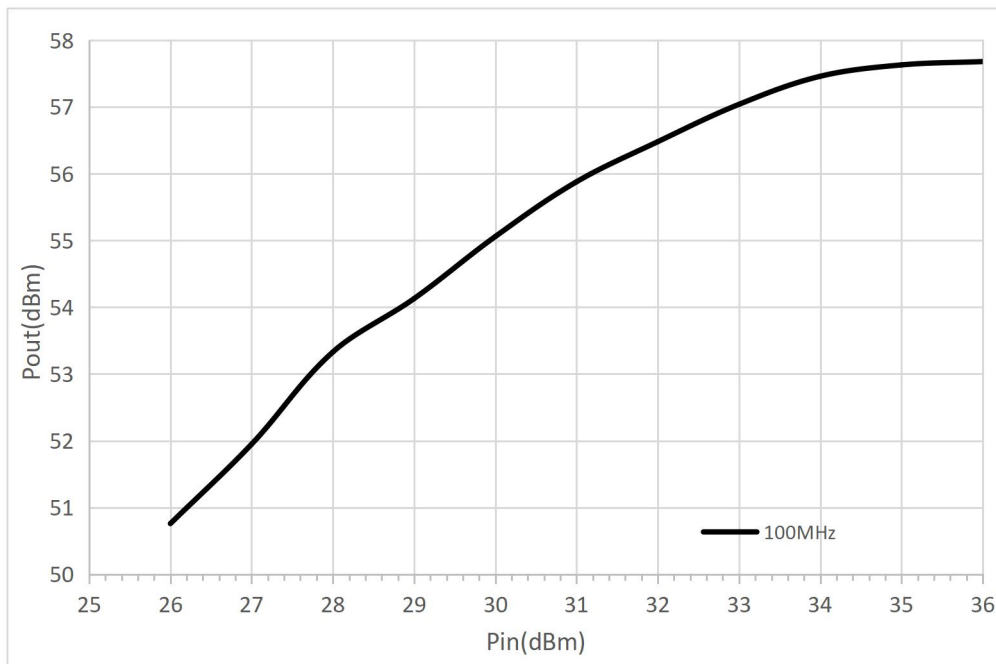
# HTH8G02P550S(B)

## 550W, 1.8 - 200 MHz LDMOS Amplifier

Product datasheet

C9,C12	4p7F	MLCC	ATC	ATC100B4R7JT
C3,C4,C6,C14	1nF	MLCC	Murata	GR321AD72E102KW01D
C7,C15	100pF	MLCC	Murata	GRM1885C1H101JA01
R3	820Ω	Wire Resistor	-	-
Coax 2,3	16.7Ω 4:1, 110 mm		-	-
Coax 4,5	16.7Ω 4:1, 100 mm		-	-
Coax 1	50Ω 2:1, 100 mm		-	-
Coax 6	50Ω 2:1, 40mm		-	-
PCB	RF35 (er = 3.5), 30 mil (0.762 mm), 35 μm (1oz)			

### Performance Plots



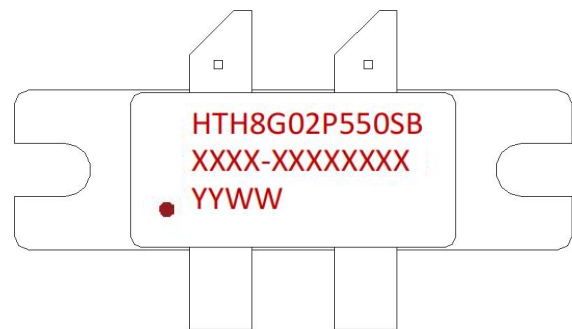
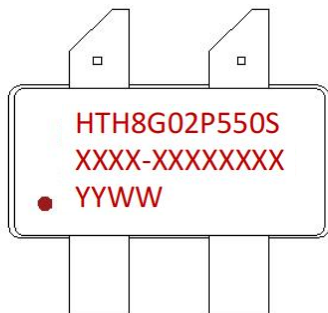
Pulsed CW, Pout vs Pin



**Pulsed CW, Gain and Efficiency vs Pout**

Test conditions unless otherwise noted: 25 °C, VDD = +50dc, IDQ= 300mA, PW = 100us, DC= 10% test on WATECH Application Board

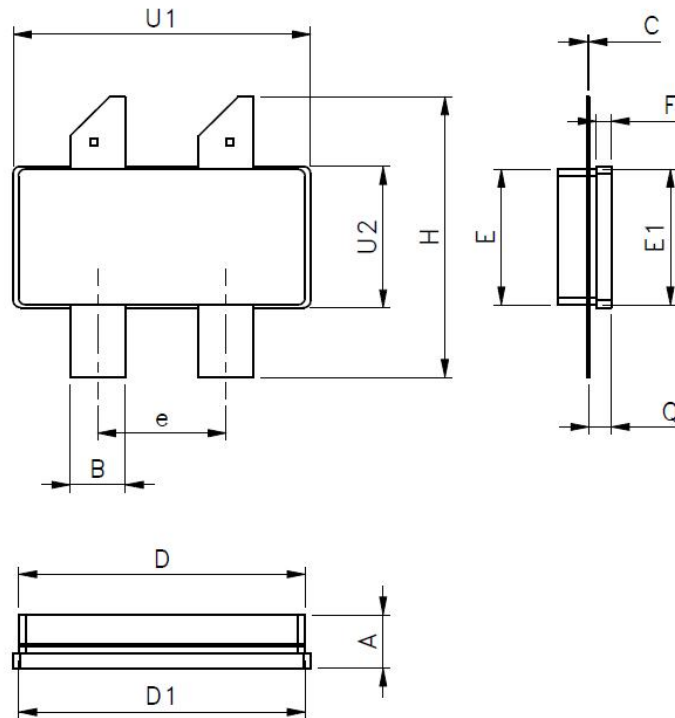
### Package Marking and Dimensions



- Line1 (fixed): Device name in W/O
- Line2 (unfixed): Marking Lot No in W/O (Sample: E596-EERA0001)
- Line3 (unfixed): Date Code

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of "Watech Product Printing Specification"

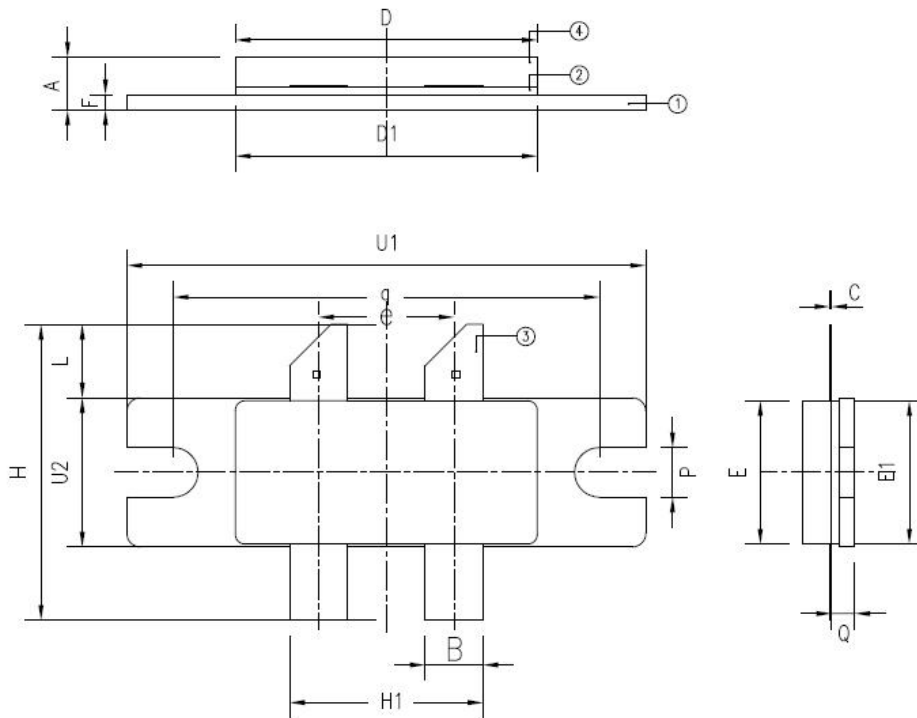
#### Marking



Symbol	Dimesions in Milimeters			Dimesions in Inches		
	Min.	Mon.	Max.	Min.	Mon.	Max.
A	3.12	3.69	4.26	0.123	0.145	0.168
B	3.69	3.81	3.93	0.145	0.150	0.155
C	-	0.11	-	-	0.004	-
D	19.61	19.81	20.01	0.772	0.780	0.788
D1	19.66	19.81	19.96	0.774	0.780	0.786
E	9.273	9.4	9.527	0.365	0.370	0.375
E1	9.28	9.4	9.52	0.365	0.370	0.375
F	0.95	1.02	1.09	0.037	0.040	0.043
H	19.38	19.43	19.48	0.763	0.765	0.767
Q	1.46	1.53	1.6	0.057	0.060	0.063
U1	20.51	20.58	20.65	0.807	0.810	0.813
U2	9.71	9.78	9.85	0.382	0.385	0.388
e	8.77	8.89	9.01	0.345	0.350	0.355

**Package Dimensions**

**ACS2110S-4L Earless Flanged Ceramic Package; 4 leads**



Symbol	Dimensions in Millimeters			Dimensions in Inches		
	Min.	Mon.	Max.	Min.	Mon.	Max.
A	3.55	3.71	3.86	0.140	0.146	0.152
B	3.68	3.81	3.94	0.145	0.150	0.155
C	0.04	0.11	0.18	0.002	0.004	0.007
D	19.61	19.81	20.01	0.772	0.780	0.788
D1	19.61	19.81	20.01	0.772	0.780	0.788
E	9.28	9.40	9.52	0.365	0.370	0.375
E1	9.28	9.40	9.52	0.365	0.370	0.375
F	0.95	1.02	1.09	0.037	0.040	0.043
H	18.93	19.43	19.93	0.745	0.765	0.785
H1	12.57	12.70	12.83	0.495	0.500	0.505
L	4.71	4.83	4.95	0.185	0.190	0.195
P	3.12	3.25	3.38	0.123	0.128	0.133
Q	1.43	1.53	1.63	0.056	0.060	0.064
q	-	27.94	-	-	1.10	-
U1	33.91	34.04	34.16	1.335	1.340	1.345
U2	9.71	9.78	9.85	0.382	0.385	0.388
e	-	8.89	-	-	0.35	-

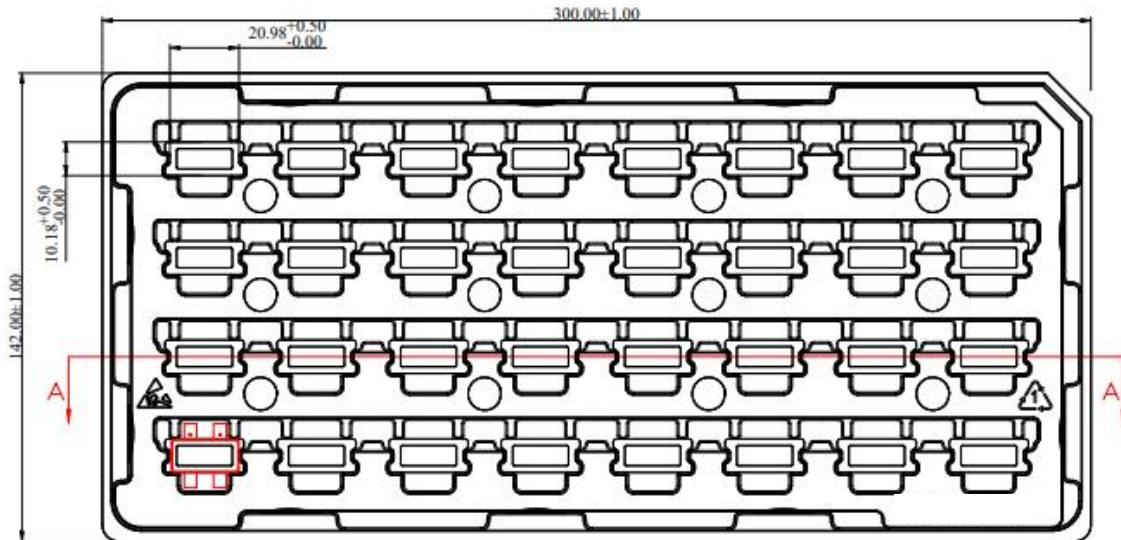
**Package Dimensions**

**ACS2110B-4L Flanged Ceramic Package; 2 mounting holes; 4 leads**

### Packing Information

#### HTH8G02P550S:

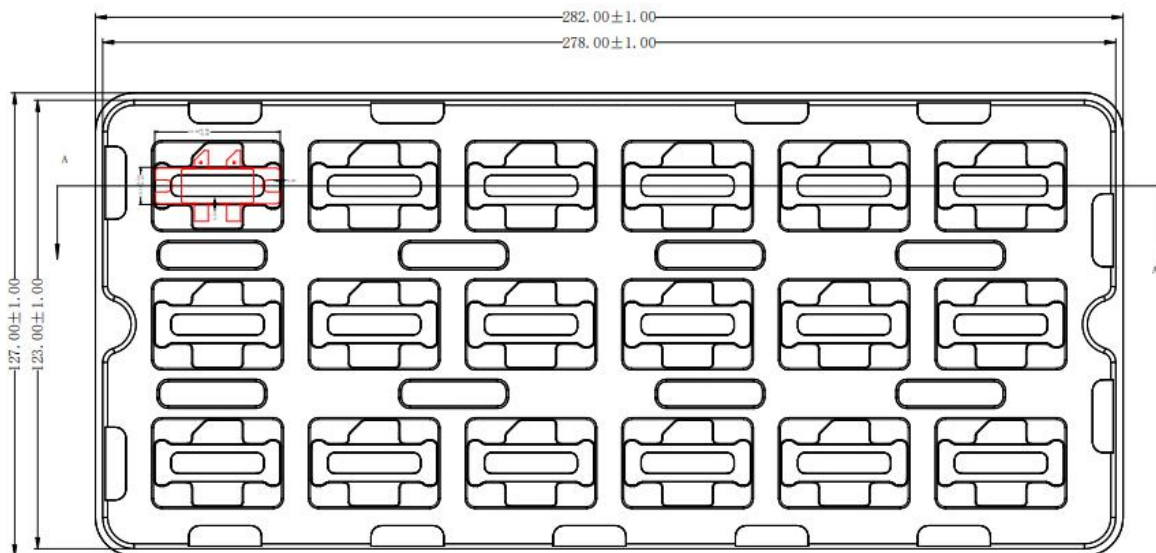
Package Type	Qty/Tray(pcs)	Qty/Box(pcs)
ACS2110S-4L	32	160



HTH8G02P550S Packaging Descriptions

#### HTH8G02P550SB:


Package Type	Qty/Tray(pcs)	Qty/Box(pcs)
ACS2110B-4L	18	90



HTH8G02P550SB Packaging Descriptions



## Handling Precautions

Parameter	Rating	Standard	
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114	
ESD – Human Body Model (MM)	Class A	EIA/JESD22-A115	
ESD – Charged Device Model (CDM)	Class III	JESD22-C101	

## RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

## Datasheet Status

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification

## Abbreviations

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform

## Revision history

Document ID	Datasheet Status	Release Date	Revision Version
Rev 1.0	Preliminary	Dec. 2021	Preliminary
Rev 1.1	Objective	March 2023	New format based on English version datasheet
Rev 2.0	Product	Sept.2023	Update TBD information
Rev 2.1	Product	Oct.2023	Update package information



# HTH8G02P550S(B) 550W, 1.8 - 200 MHz LDMOS Amplifier

Product datasheet

## Contact Information

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For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

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- Email: [MKT@huatai-elec.com](mailto:MKT@huatai-elec.com)

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- Email: [MKT@huatai-elec.com](mailto:MKT@huatai-elec.com)

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